



2SB1274/2SD1913

60V/3A Low-Frequency Power Amplifier Applications

Applications

- General power amplifier.

Package Dimensions

unit : mm
2041A

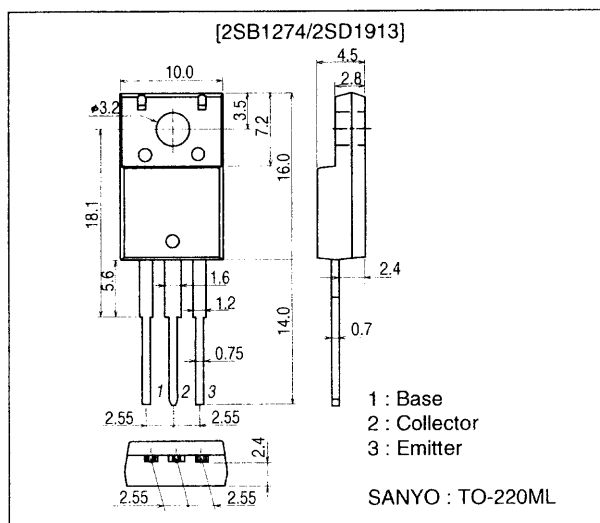
Features

- Wide ASO (Adoption of MBIT process).
- Low saturation voltage.
- High reliability.
- High breakdown voltage.
- Micaless package facilitating mounting.

Specifications

():2SB1274

Absolute Maximum Ratings at Ta=25°C



Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CB0}		(-)-60	V
Collector-to-Emitter Voltage	V _{CE0}		(-)-60	V
Emitter-to-Base Voltage	V _{EB0}		(-)-6	V
Collector Current	I _C		(-)-3	A
Collector Current (Pulse)	I _{CP}		(-)-8	A
Collector Dissipation	P _C		2	W
		T _C =25°C	20	W
Junction Temperature	T _J		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at $T_a=25^{\circ}\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=(-)40V, I_E=0$			$(-)100$	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=(-)4V, I_C=0$			$(-)100$	μA

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SANYO Electric Co., Ltd. Semiconductor Company

TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

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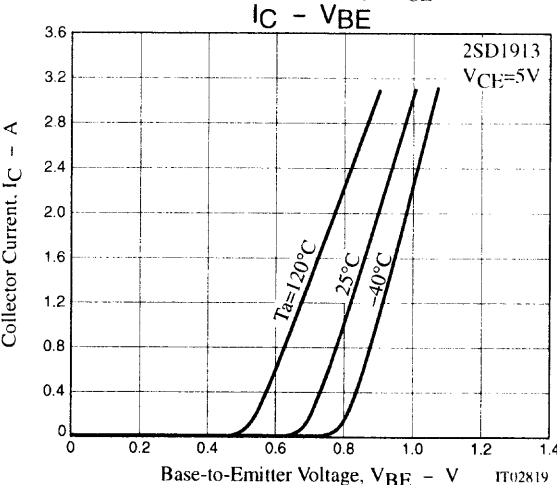
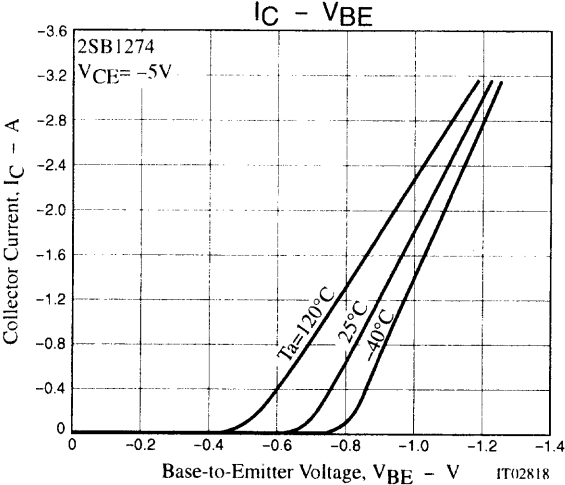
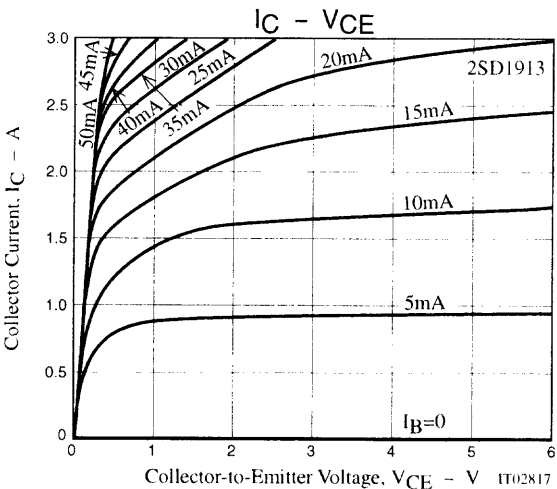
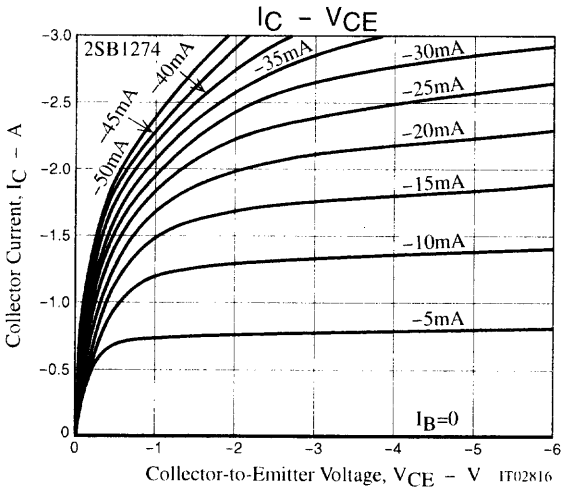
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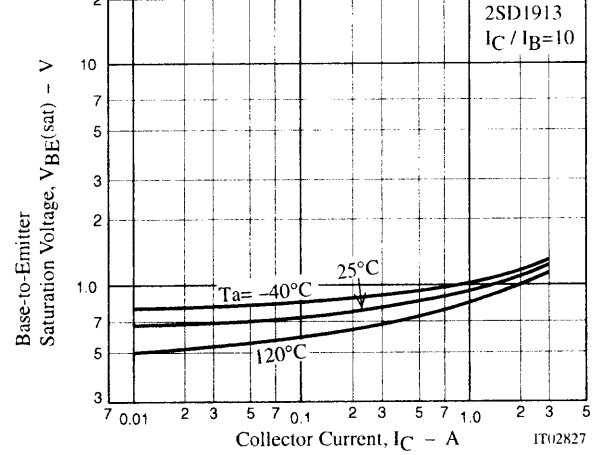
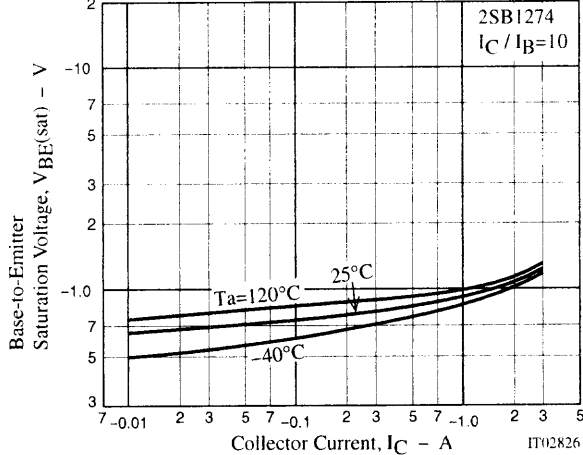
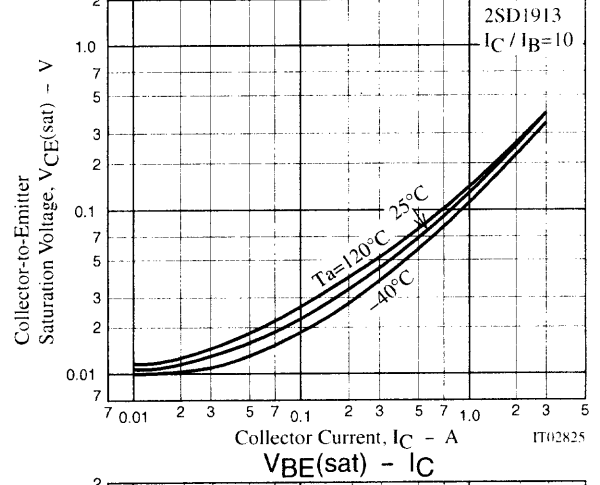
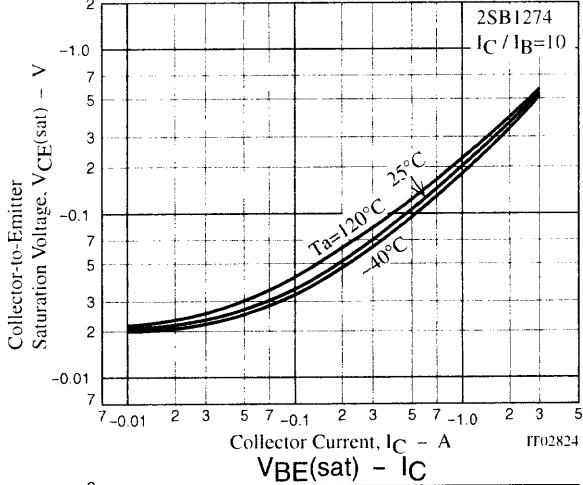
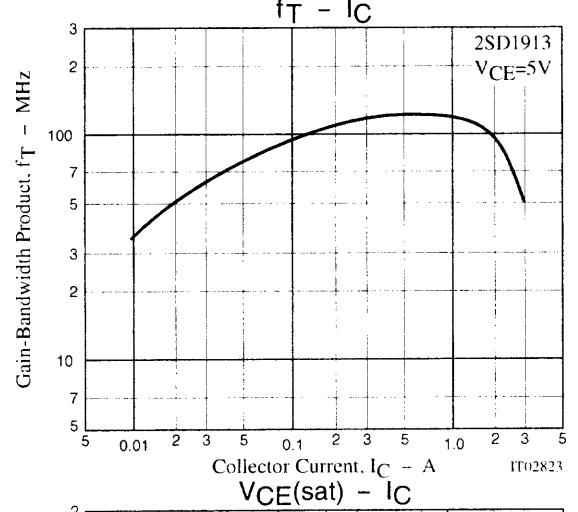
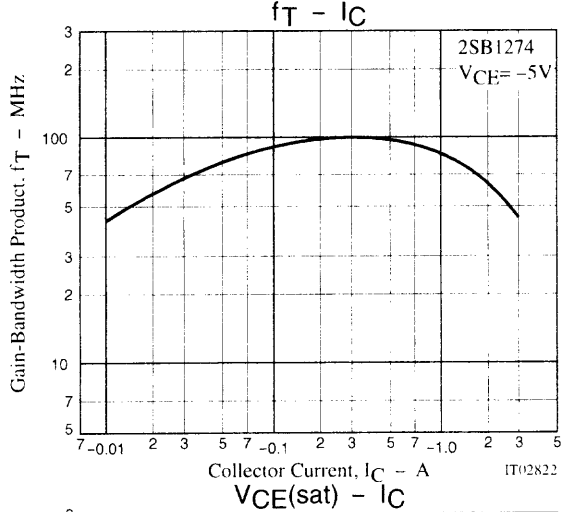
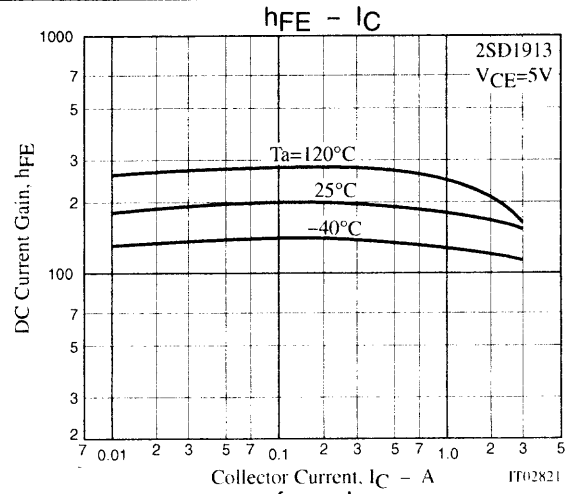
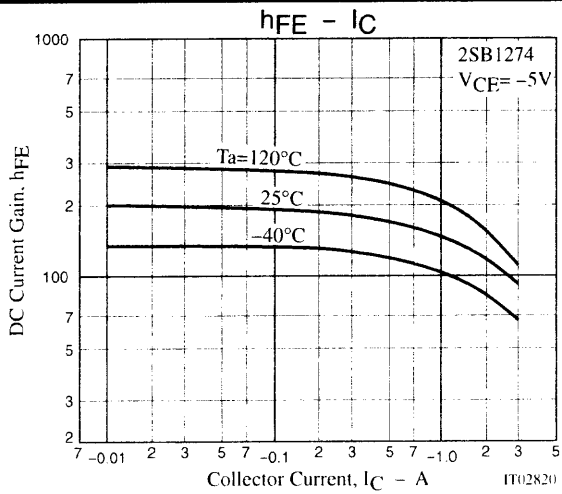
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
DC Current Gain	h_{FE1}	$V_{CE}=(-)5V, I_C=(-)0.5A$	70*		280*	
	h_{FE2}	$V_{CE}=(-)5V, I_C=(-)3A$	20			
Gain-Bandwidth Product	f_T	$V_{CE}=(-)5V, I_C=(-)0.5A$		100		MHz
Output Capacitance	C_{ob}	$V_{CB}=(-)10V, f=1MHz$		(60)40		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)2A, I_B=(-)0.2A$		(-)0.4	(-)1	V
Base-to-Emitter Voltage	V_{BE}	$V_{CE}=(-)5V, I_C=(-)0.5A$		(-)0.8	(-)1	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)1mA, I_E=0$	(-)60			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=5mA, R_{BE}=\infty$	(-)60			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)1mA, I_C=0$	(-)6			V

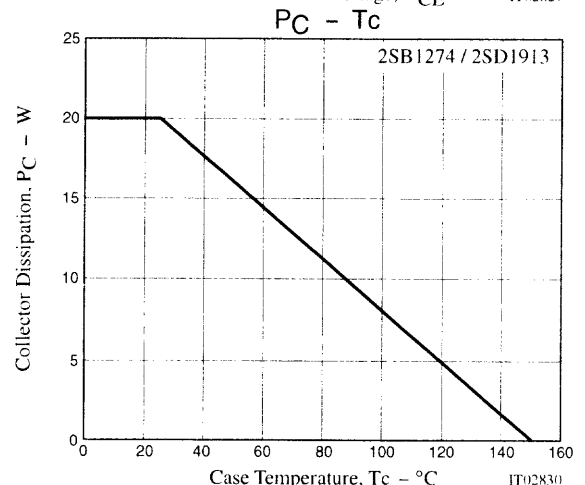
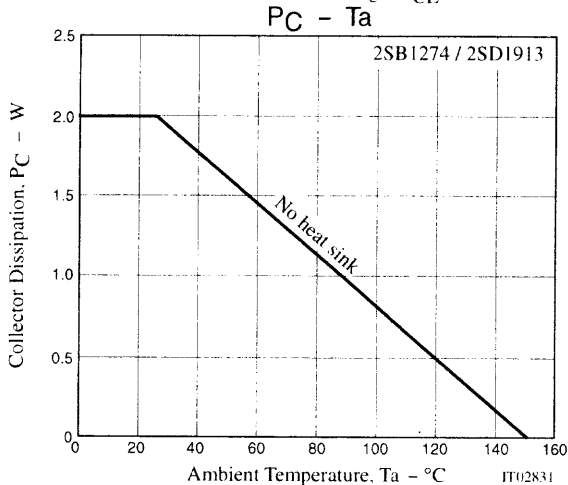
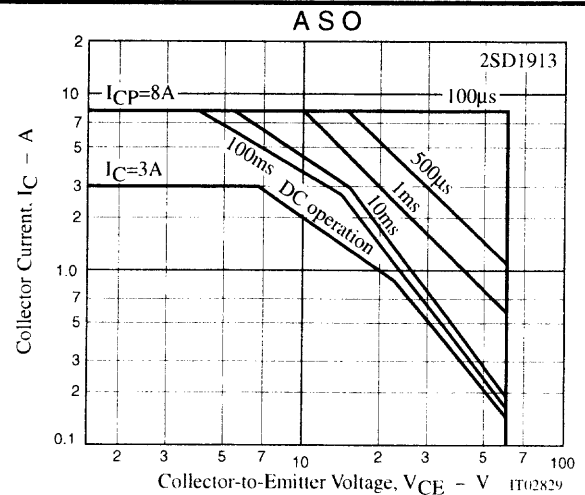
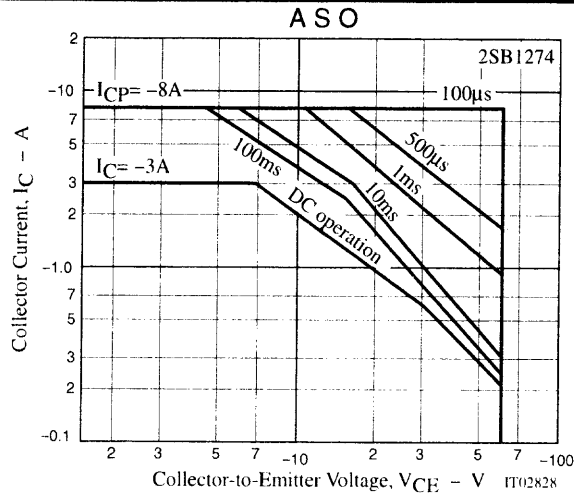
* : The 2SBB1274 / 2SD1913 are classified by 0.5A h_{FE} as follows :

Rank	Q	R	S
h_{FE}	70 to 140	100 to 200	140 to 280



2SB1274/2SD1913





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